

SEMITOP[®]4

IGBT module

SK100GH12T4T

Features

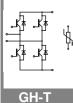
- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances
 by aluminium oxide substrate
- New IGBT4 Technology
- CAL 4 technology FWD
- Integrated NTC Temperature sensor

Typical Applications*

Voltage regulator

Absolute	e Maximum Ratings	T _s =	25 °C, unless otherwise	specified
Symbol	Conditions		Values	Units
IGBT				
V _{CES}	T _j = 25 °C		1200	V
I _C	T _j = 175 °C	T _s = 25 °C	126	А
		T _s = 70 °C	100	А
I _{CRM}	I_{CRM} = 3 x I_{Cnom} , $t_p \le 1ms$		300	А
V _{GES}			±20	V
t _{psc}	V_{CC} = 800 V; $V_{GE} \le 15$ V; VCES < 1200 V	T _j = 150 °C	10	μs
Inverse I	Diode			
I _F	T _j = 175 °C	T _s = 25 °C	102	А
		T _s = 70 °C	81	А
I _{FRM}	I_{FRM} = 3 x I_{Fnom} , $t_p \le 1ms$		300	А
I _{FSM}	$t_p = 10 \text{ ms}; \text{ half sine wave}$	T _j = 150 °C	715	А
Module			·	
I _{t(RMS)}				А
T _{vj}			-40 +175	°C
T _{stg}			-40 +125	°C
V _{isol}	AC, 1 min.		2500	V

Characteristics T _c =			25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT			_			
V _{GE(th)}	V_{GE} = V_{CE} , I_C = 3,4 mA		5	5,8	6,5	V
I _{CES}	V_{GE} = 0 V, V_{CE} = V_{CES}	T _j = 25 °C			1,68	mA
		T _j = 125 °C		0,4		mA
I _{GES}	V _{CE} = 0 V, V _{GE} = 20 V	T _j = 125 °C			1200	nA
V _{CE0}		T _j = 25 °C		0,8	0,9	V
		T _j = 150 °C		0,7	0,8	V
r _{CE}	V _{GE} = 15 V	T _j = 25°C		10		mΩ
		T _j = 150°C		15		mΩ
V _{CE(sat)}	I _{Cnom} = 100 A, V _{GE} = 15 V			1,8	2	V
		T _j = 150°C _{chiplev.}		2,2	2,4	V
C _{ies}				5,54		nF
C _{oes}	V_{CE} = 25, V_{GE} = 0 V	f = 1 MHz		0,41		nF
C _{res}				0,32		nF
Q_{G}	V _{GE} =-7V+15V			750		nC
R _{Gint}	T _j = 25 °C			2		Ω
t _{d(on)}				63		ns
t _r	$R_{Gon} = 16 \Omega$	V _{CC} = 600V		65		ns
E _{on}	di/dt = 1800 A/µs	I _C = 100A		16,6		mJ
t _{d(off)} t	R _{Goff} = 16 Ω di/dt = 1800 A/μs	T _j = 150 °C		521 80		ns ns
t _r ⊨				10		mJ
E _{off}				-		
R _{th(j-s)}	per IGBT			0,43		K/W





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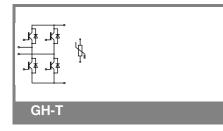
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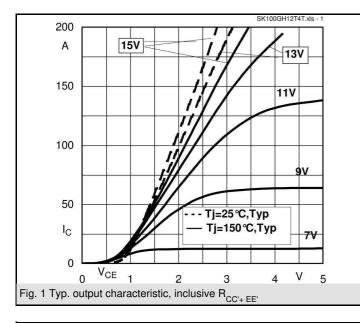
Typical Applications*

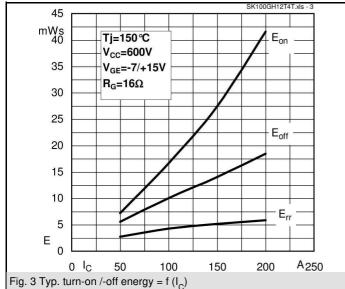
Voltage regulator

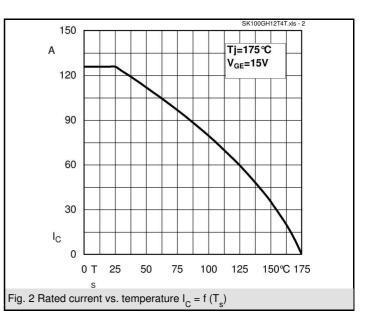
Characteristics								
Symbol	Conditions		min.	typ.	max.	Units		
Inverse								
$V_F = V_{EC}$	I _{Fnom} = 100 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}		2,2	2,5	V		
		T _j = 150 °C _{chiplev} .		2,1	2,45	V		
V _{F0}		T _j = 25 °C		1,3	1,5	V		
		T _j = 150 °C		0,9	1,1	V		
r _F		T _i = 25 °C		9,5	10,5	mΩ		
		T _j = 150 °C		13	14	mΩ		
I _{RRM}	I _F = 100 A	T _i = 150 °C		52		Α		
Q _{rr}	di/dt = 1800 A/µs			14		μC		
Err	V _{CC} =600V			5,2		mJ		
$R_{th(j-s)D}$	per diode			0,62		K/W		
	eling Diode							
$V_F = V_{EC}$	I _{Fnom} = A; V _{GE} = V					V		
V _{F0}		$T_{j} = °C$ $T_{j} = °C$ $T_{j} = °C$				V		
r _F		T _j = °C				V		
I _{RRM}	I _F = A	T _i = °C				А		
Q _{rr}						μC		
Err						mJ		
	per diode					K/W		
M _s	to heat sink		2,5		2,75	Nm		
w				60		g		
Tempera	ture sensor					•		
R ₁₀₀	T _s = 100°C (R ₂₅ =5kΩ)			493±5%		Ω		

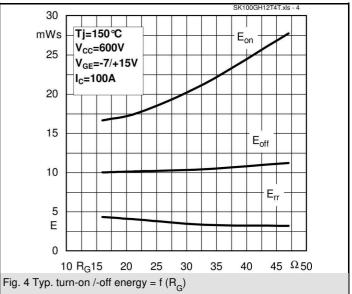


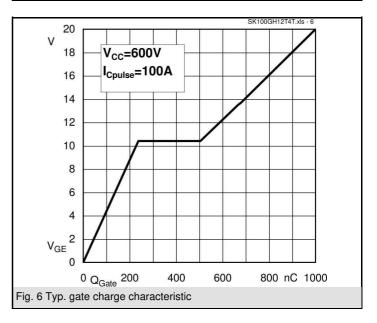
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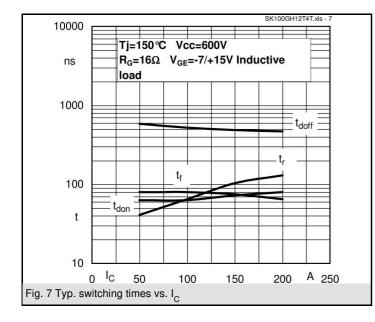


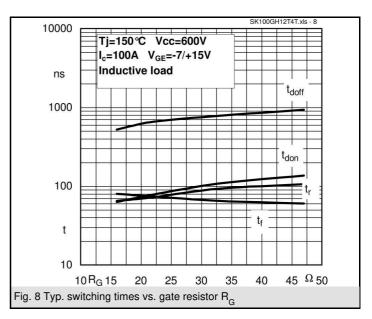


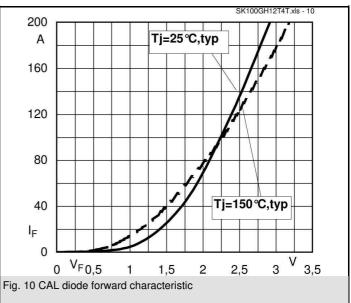


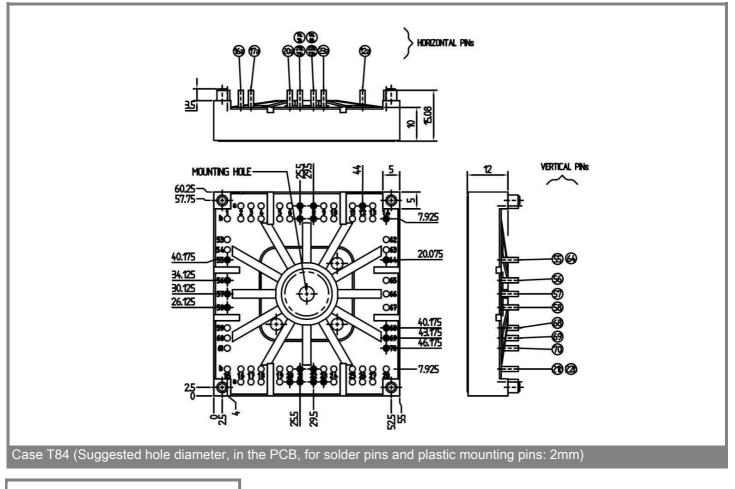


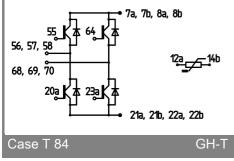












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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